## **MOSFET** – Single, N-Channel with ESD Protection, Small Signal, SC-75 and SC-89 20 V, 915 mA

#### Features

- Low R<sub>DS(on)</sub> Improving System Efficiency
- Low Threshold Voltage, 1.5 V Rated
- ESD Protected Gate
- NV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- Pb-Free Packages are Available

#### Applications

- Load/Power Switches
- Power Supply Converter Circuits
- Battery Management
- Portables like Cell Phones, PDAs, Digital Cameras, Pagers, etc.

#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise stated)

Parameter			Symbol	Value	Units
Drain-to-Source Voltage			V <sub>DSS</sub>	20	V
Gate-to-Source Voltage			V <sub>GS</sub>	±6.0	V
Continuous Drain	Steady State	$T_A = 25^{\circ}C$	۱ <sub>D</sub>	915	mA
Current (Note 1)		$T_A = 85^{\circ}C$		660	
Power Dissipation (Note 1)	Steady State		P <sub>D</sub>	300	mW
Pulsed Drain Current	t <sub>p</sub> =10 μs		I <sub>DM</sub>	1.3	А
Operating Junction and Storage Temperature			T <sub>J</sub> , T <sub>STG</sub>	–55 to 150	°C
Continuous Source Current (Body Diode)			۱ <sub>S</sub>	280	mA
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			Τ <sub>L</sub>	260	°C

#### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Units
Junction-to-Ambient - Steady State (Note 1) SC-75 / SOT-416 SC-89	$R_{\theta JA}$	416 400	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface mounted on FR4 board using 1 in sq pad size

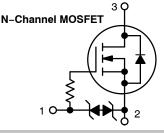
(Cu area = 1.127 in sq [1 oz] including traces).



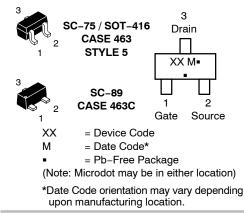
## **ON Semiconductor®**

#### http://onsemi.com

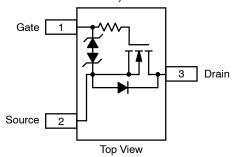
V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> TYP	I <sub>D</sub> MAX
20 V	0.127 Ω @ 4.5 V	
	0.170 Ω @ 2.5 V	915 mA
	0.242 Ω @ 1.8 V	01011/
	0.500 Ω @ 1.5 V	



#### MARKING DIAGRAM & PIN ASSIGNMENT







#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 4 of this data sheet.

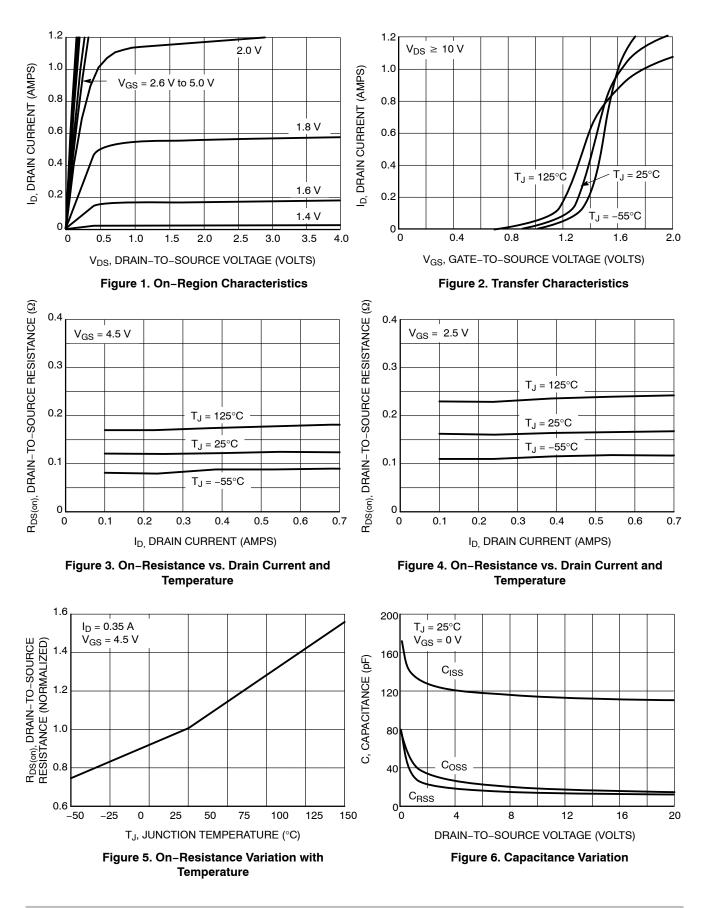
#### ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = 25°C unless otherwise stated)

Parameter	Symbol	Test Cond	lition	Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS}$ = 0 V, $I_D$ = 250 $\mu$ A		20	26		V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V <sub>(BR)DSS</sub> /T <sub>J</sub>				18.4		mV/°C
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>GS</sub> = 0 V, V <sub>E</sub>	<sub>os</sub> = 16 V			100	nA
Gate-to-Source Leakage Current	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS}$	<sub>S</sub> = ±4.5 V			±1.0	μA
ON CHARACTERISTICS (Note 2)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}, I_D$	= 250 μA	0.45	0.76	1.1	V
Negative Threshold Temperature Coefficient	V <sub>GS(TH)</sub> /T <sub>J</sub>				-2.15		mV/°C
Drain-to-Source On Resistance	R <sub>DS(on)</sub>	$V_{GS}$ = 4.5 V, I <sub>D</sub>	= 600 mA		127	230	mΩ
		$V_{GS}$ = 2.5 V, I <sub>D</sub>	= 500 mA		170	275	
		V <sub>GS</sub> = 1.8 V, I <sub>D</sub>	= 350 mA		242	700	
		V <sub>GS</sub> = 1.5 V, I <sub>[</sub>	<sub>0</sub> = 40 mA		500	950	
Forward Transconductance	<b>g</b> fs	$V_{DS}$ = 10 V, $I_D$	= 400 mA		1.4		S
CHARGES AND CAPACITANCES							
Input Capacitance	C <sub>ISS</sub>				110		pF
Output Capacitance	C <sub>OSS</sub>	V <sub>GS</sub> = 0 V, f = 1.0 MHz, V <sub>DS</sub> = 16 V			16		
Reverse Transfer Capacitance	C <sub>RSS</sub>				12		
Total Gate Charge	Q <sub>G(TOT)</sub>				1.82		nC
Threshold Gate Charge	Q <sub>G(TH)</sub>	V <sub>GS</sub> = 4.5 V, V <sub>I</sub>	<sub>DS</sub> = 10 V,		0.2		
Gate-to-Source Charge	Q <sub>GS</sub>	$V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V},$ $I_D = 0.2 \text{ A}$			0.3		
Gate-to-Drain Charge	Q <sub>GD</sub>				0.42		
SWITCHING CHARACTERISTICS (No	te 3)						
Turn-On Delay Time	t <sub>d(ON)</sub>	$V_{GS}$ = 4.5 V, $V_{DD}$ = 10 V, $I_{D}$ = 0.2 A, $R_{G}$ = 10 $\Omega$			3.7		ns
Rise Time	t <sub>r</sub>				4.4		
Turn-Off Delay Time	t <sub>d(OFF)</sub>				25		
Fall Time	t <sub>f</sub>				7.6		
DRAIN-SOURCE DIODE CHARACTE	RISTICS						
Forward Diode Voltage	V <sub>SD</sub>	V <sub>GS</sub> = 0 V,	$T_J = 25^{\circ}C$		0.67	1.1	V
	ls	I <sub>S</sub> = 200 mA	T <sub>J</sub> = 125°C		0.54		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Test: pulse width  $\leq$  300 µs, duty cycle  $\leq$  2%.

3. Switching characteristics are independent of operating junction temperatures.

### **TYPICAL ELECTRICAL CHARACTERISTICS**



## **TYPICAL ELECTRICAL CHARACTERISTICS**

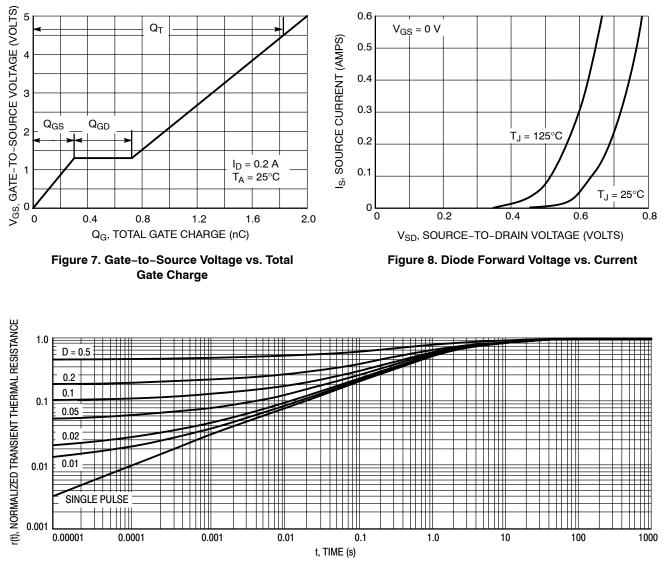


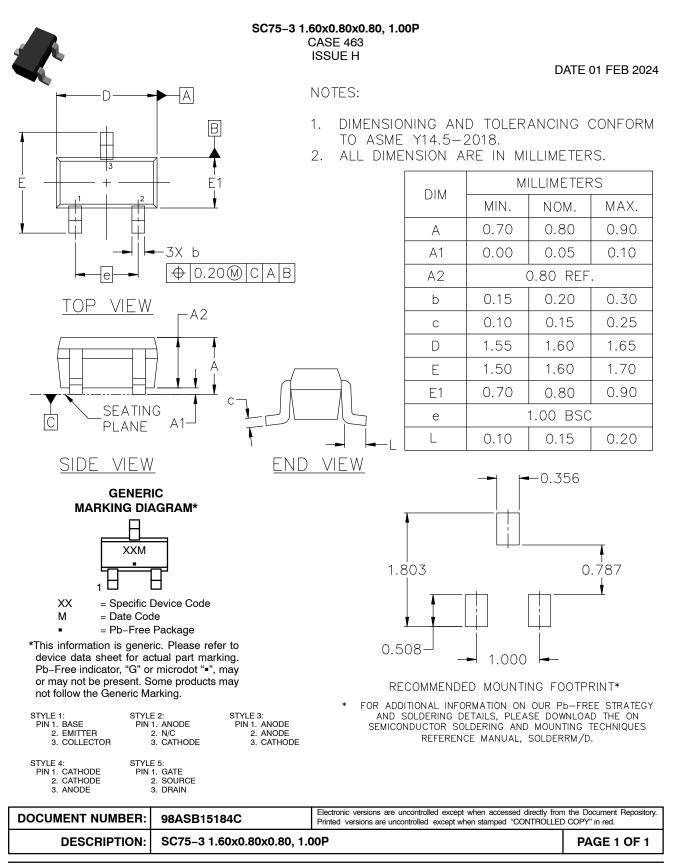
Figure 9. Normalized Thermal Response

#### ORDERING INFORMATION

Device	Marking	Package	Shipping <sup>†</sup>
NTA4153NT1	TR	SC-75 / SOT-416	3000 / Tape & Reel
NTA4153NT1G	TR	SC-75 / SOT-416 (Pb-Free)	3000 / Tape & Reel
NTE4153NT1G	TP	SC-89 (Pb-Free)	3000 / Tape & Reel
NVA4153NT1G	VR	SC-75 / SOT-416 (Pb-Free)	3000 / Tape & Reel
NVE4153NT1G	VP	SC–89 (Pb–Free)	3000 / Tape & Reel

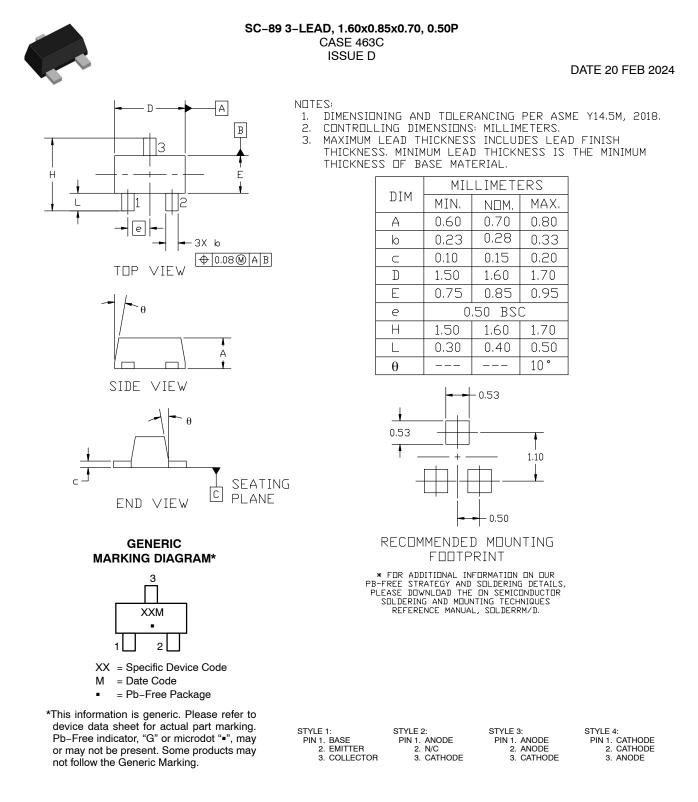
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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